μP Supervisory Circuits

The MAX707/708 are cost–effective system supervisor circuits designed to monitor V_{CC} in digital systems and provide a reset signal to the host processor when necessary. No external components are required.

The reset output is driven active within 20 µsec of V_{CC} falling through the reset voltage threshold. Reset is maintained with 200 mS of delay time after V_{CC} rise above the reset threshold. The MAX707/708 have a low quiescent current of 12 µA at V_{CC} = 3.3 V, an active–high RESET and active–low RESET with a push–pull output. The output is guaranteed valid down to V_{CC} = 1.0 V. The MAX707/708 have a Manual Reset \overline{MR} input and a +1.25 V threshold detector for power–fail input PFI. These devices are available in a Micro8 and SOIC–8 package.

Features

- Precision Supply-Voltage Monitor
 MAX707: 4.63 V Reset Threshold Voltage
 MAX708: Standard Reset Threshold Voltages (Typical):
 4.38 V, 3.08 V, 2.93 V, 2.63 V
- Reset Threshold Available from 1.6 V to 4.9 V with 100 mV Increments (Factory Option)
- 200 mS (Typ) Reset Timeout Delay
- 12 μ A ($V_{CC} = 3.3 \text{ V}$) Quiescent Current
- Active_High and Active_Low Reset Output
- Guaranteed RESET_L and RESET Output Valid to V_{CC} = 1.0 V
- Voltage Monitor for Power-Fail or Low-Battery Warning
- 8 Pin SOIC or Micro8 Package
- Pb-Free Packages are Available

Applications

- Computers
- Embedded System
- Battery Powered Equipment
- Critical μP Power Supply Monitor



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MARKING DIAGRAMS



Micro8™ CUA SUFFIX CASE 846A



xxx = Specific Device Code A = Assembly Location

Y = Year W = Week

= Pb-Free Package



SOIC-8 ESA SUFFIX CASE 751



xxxxx = Specific Device Code AL = Assembly Lot Code

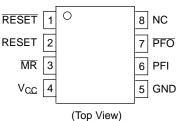
Y = Year W = Week

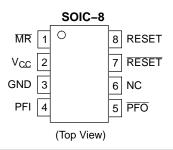
■ = Pb–Free Package

(Note: Microdot may be in either location)

PIN CONFIGURATION

Micro8





ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

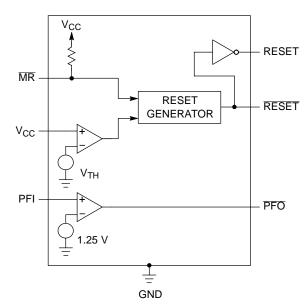


Figure 1. Representative Block Diagram

MAXIMUM RATINGS (Note 1)

Rating		Symbol	Value	Unit
Supply Voltage		V _{CC}	6.0	V
Output Voltage		V _{out}	-0.3 to (V _{CC} + 0.3)	V
Output Current (All Outputs)		l _{out}	20	mA
Input Current (V _{CC} and GND)		l _{in}	20	mA
Thermal Resistance Junction-to-Air	Micro8 SOIC-8	$R_{ hetaJA}$	248 187	°C/W
Operating Ambient Temperature		T _A	-40 to +85	°C
Storage Temperature Range		T _{stg}	-40 to +125	°C
LatchUp Performance	Positive Negative	I _{LATCHUP}	300 280	mA

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

- 1. This device series contains ESD protection and exceeds the following tests: Human Body Model 2000 V per MIL-STD-883, Method 3015. Machine Model Method 200 V.

2. The maximum package power dissipation limit must not be exceeded.
$$P_D = \frac{T_J(max) - T_A}{R_{\theta JA}} \qquad \text{with } T_{J(max)} = 150^{\circ}\text{C}$$

ELECTRICAL CHARACTERISTICS ($V_{CC} = 1.0 \text{ V}$ to 5.5 V, $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, unless otherwise noted. Typical values are at $T_A = 25^{\circ}\text{C}$, $V_{CC} = 3.3 \text{ V}$.)

Characteristics	Symbol	Min	Тур	Max	Unit
Operating Voltage Range	V _{CC}	1.0	-	5.5	V
Supply Current $V_{CC} = 3.3 \text{ V}$ $V_{CC} = 5.5 \text{ V}$	Icc		12 16	22 28	μΑ
Reset Threshold	V _{TH}				V
MAX707 $T_A = +25^{\circ}C$ $T_A = -40^{\circ}C$ to +85°C MAX708		4.56 4.50	4.63	4.70 4.75	
$T_A = +25$ °C $T_A = -40$ °C to +85°C MAX708T		4.31 4.25	4.38	4.45 4.50	
$T_A = +25^{\circ}C$ $T_A = -40^{\circ}C$ to +85°C MAX708S		3.03 3.00	3.08	3.13 3.15	
$T_A = +25^{\circ}C$ $T_A = -40^{\circ}C$ to +85°C MAX708R		2.89 2.85	2.93	2.97 3.00	
$T_A = +25$ °C $T_A = -40$ °C to +85°C		2.59 2.55	2.63	2.67 2.70	
Reset Threshold Hysteresis	V _{HYS}	-	0.01 V _{TH}	-	mV
V_{CC} Falling Reset Delay ($V_{CC} = V_{TH} + 0.2 \text{ V to } V_{TH} - 0.2 \text{ V}$)	t _{PD}	-	20	-	μS
Reset Active Timeout Period	t _{RP}	140	200	330	mS
RESET_L, RESET_H Output Low Voltage $V_{CC} \ge 1.0 \text{ V}, I_{ol} = 100 \mu\text{A}$ $V_{CC} > 2.7 \text{ V}, I_{ol} = 1.2 \text{ mA}$ $V_{CC} > 4.5 \text{ V}, I_{ol} = 3.2 \text{ mA}$	V _{ol}	- - -	- - -	0.3 0.3 0.3	V
RESET_L, RESET_H Output High Voltage $\begin{array}{l} V_{CC} \geq 1.0 \text{ V}, I_{oh} = 50 \mu\text{A} \\ V_{CC} > 2.7 \text{ V}, I_{oh} = 500 \mu\text{A} \\ V_{CC} > 4.5 \text{ V}, I_{oh} = 800 \mu\text{A} \end{array}$	V _{oh}	0.8 V _{CC} 0.8 V _{CC} 0.8 V _{CC}	- - -	- - -	V
MR_L Pull-up Resistance	R _{MRI}	50	-	-	ΚΩ
MR_L Pulse Width (V_{TH} (max) $< V_{CC} < 5.5 V$)	t _{MR}	1.0	-	-	μS
MR_L Glitch Rejection (V_{TH} (max) $< V_{CC} < 5.5$ V)	-	-	0.1	-	μS
MR_L High_level Input Threshold (V_{TH} (max) $< V_{CC} < 5.5 V$)	V _{IH}	0.7 V _{CC}	-	-	V
MR_L Low_level Input Threshold (V_{TH} (max) $< V_{CC} < 5.5 V$)	V_{IL}	-	-	0.3 V _{CC}	V
MR_L to RESET_L and RESET_H Output Delay (V $_{\rm TH}$ (max) $<$ V $_{\rm CC}$ $<$ 5.5 V)	t _{MD}	_	0.2	-	μS
PFI Input Threshold (V _{CC} = 3.3 V, PFI Falling)	_	1.20	1.25	1.3	V
PFI Input Current	-	-250	0.01	250	nA
PFI to PFO Delay (V _{CC} = 3.3 V, V _{OVERDRIVE} = 15 mV)	-	-	3.0	-	μS
PFO_L Output Low Voltage $V_{CC} = 2.7 \text{ V}, I_{ol} = 1.2 \text{ mA}$ $V_{CC} = 4.5 \text{ V}, I_{ol} = 3.2 \text{ mA}$	V _{ol}	- -	- -	0.3 0.3	V
PFO_L Output High Voltage V_{CC} = 2.7 V, I_{oh} = 500 μA V_{CC} = 4.5 V, I_{oh} = 800 μA	V _{oh}	0.8 V _{CC}	- -	- -	V

PIN DESCRIPTION (Pin No. with parentheses is for Micro8 package.)

Pin No.	Symbol	Description
1 (3)	MR	Manual Reset Input. \overline{MR} can be driven from TTL/CMOS logic or from a manual Reset switch. This input, when floating, is internally pulled up to V_{CC} with 50 k Ω resistor.
2 (4)	V _{CC}	Supply Voltage: C = 100 nF is recommended as a bypass capacitor between V _{CC} and GND.
3 (5)	GND	Ground Reference
4 (6)	PFI	Power Fail Voltage Monitor Input. When PFI is less than 1.25 V, PFO goes low. Connect PFI to GND or V _{CC} when not used.
5 (7)	PFO	Power Fail Monitor Output. When PFI is less than 1.25 V, it goes low and sinks current. Otherwise, it remains high.
6 (8)	NC	Non-connective Pin
7 (1)	RESET	Active Low $\overline{\text{RESET}}$ can be triggered by V_{CC} below the threshold level or by a low signal on $\overline{\text{MR}}$. It remains low for 200 ms (typ.) after V_{CC} rises above the reset threshold.
8 (2)	RESET	Active high RESET output the inverse of RESET one.

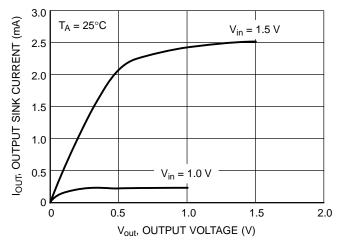


Figure 2. MAX707/708 Series 1.60 V Reset Output Sink Current vs. Output Voltage

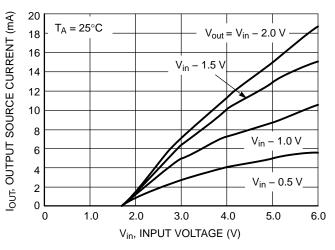


Figure 3. MAX707/708 Series 1.60 V Reset Output Source Current vs. Input Voltage

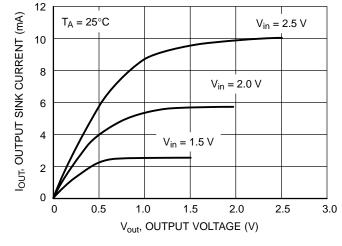


Figure 4. MAX707/708 Series 2.93 V Reset Output Sink Current vs. Output Voltage

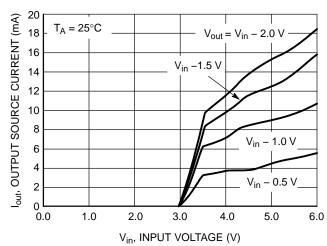
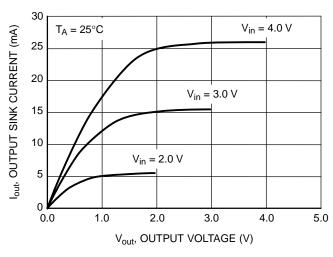


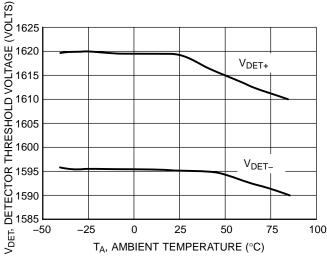
Figure 5. MAX707/708 Series 2.93 V Reset Output Source Current vs. Input Voltage



20 lout, OUTPUT SOURCE CURRENT (mA) 18 T_A = 25°C 16 $V_{out} = V_{in} - 2.0 V$ 14 12 1.5 V 10 V_{in} – 1.0 V 8 6 4 $V_{in} - 0.5 \$ 2 0.0 1.0 2.0 3.0 4.0 5.0 6.0 V_{in}, INPUT VOLTAGE (V)

Figure 6. MAX707/708 Series 4.90 V Reset Output Sink Current vs. Output Voltage

Figure 7. MAX707/708 Series 4.90 V Reset Output Source Current vs. Input Voltage



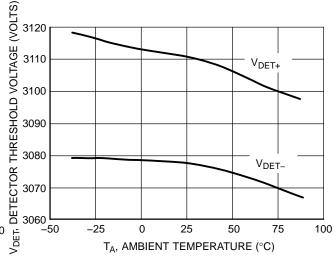
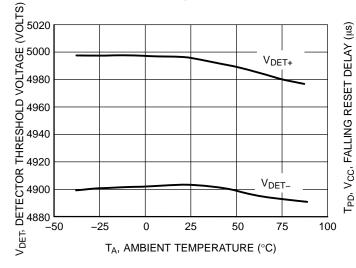


Figure 8. MAX707/708 Series 1.60 V Detector Threshold Voltage vs. Temperature

Figure 10. MAX707/708 Series 2.93 V Detector Threshold Voltage vs. Temperature



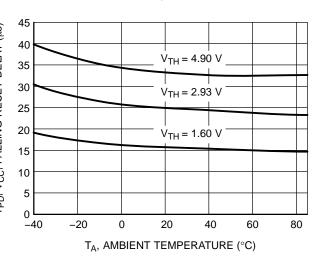


Figure 9. MAX707/708 Series 4.90 V Detector Threshold Voltage vs. Temperature

Figure 11. MAX707/708 Series V_{CC} Falling Reset Delay vs. Temperature

APPLICATIONS INFORMATION

Microprocessor Reset

To generate a processor reset, the manual Reset input allows different reset sources. A pushbutton switch can be

one of these. It is effectively debounced by the 1.0 μ s minimum reset pulse width. As \overline{MR} is TTL/CMOS logic compatible, it can be driven by an external logic line.

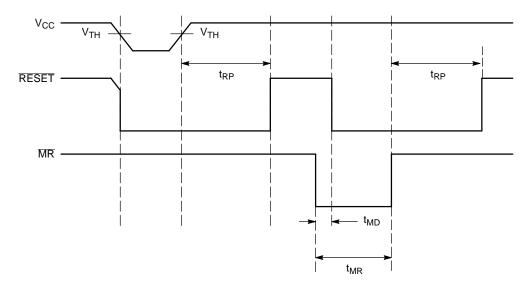


Figure 12. RESET and MR Timing

V_{CC} Transient Rejection

The MAX707/708 provides accurate V_{CC} monitoring and reset timing during power–up, power–down, and brownout/sag conditions, and rejects negative glitches on the power supply line. Figure 13 shows the maximum transient duration vs. maximum negative excursion

(overdrive) for glitch rejection. For a given overdrive, the point of the curve is the maximum width of the glitch allowed before the device generates a reset signal. Transient immunity can be improved by adding a capacitor (100 nF for example) in close proximity to the V_{CC} pin of the MAX707/708.

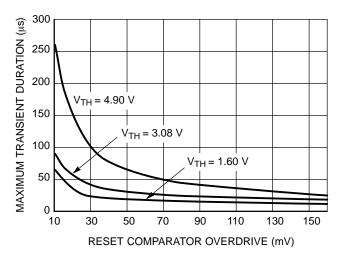
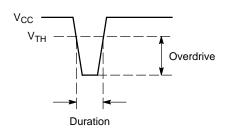


Figure 13. Maximum Transient Duration vs. Overdrive for Glitch Rejection at 25°C



RESET Signal Integrity During Power-Down

The MAX707/708 \overline{RESET} output is valid until V_{CC} falls below 1.0 V. Then, the output becomes an open circuit and no longer sinks current. This means CMOS logic inputs of the μP will be floating at an undetermined voltage. Most digital systems are completely shutdown well above this voltage. However, in the case \overline{RESET} must be maintained valid to $V_{CC}=0$ V, a pull down resistor must be connected from \overline{RESET} to ground to discharge stray capacitances and hold the output low (Figure 14). This resistor value, though not critical, should be chosen large enough not to load \overline{RESET} and small enough to pull it to ground. $R = 100 \text{ k}\Omega$ will be suitable for most applications.

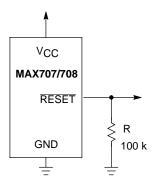


Figure 14. Ensuring \overline{RESET} Valid to $V_{CC} = 0$ V

Interfacing with µPs with Bidirectional I/O Pins

Some μPs have bidirectional reset pins. If, for example, the \overline{RESET} output is driven high and the μP wants to put it low, indeterminate logic level may result. This can be avoided by adding a 4.7 k Ω resistor in series with the output of the MAX707/708 (Figure 15). If there are other components in the system that require a reset signal, they should be buffered so as not to load the reset line. If the other

V_{CC 1} V_{CC} 3 Vcc V_CC ≶ R1 RESET RESET MAX707/708 μР $\overline{\mathsf{MR}}$ PFI PFO **GND GND** ÷ R2 R3

components are required to follow the reset I/O of the μ P, the buffer should be connected as shown with the solid line.

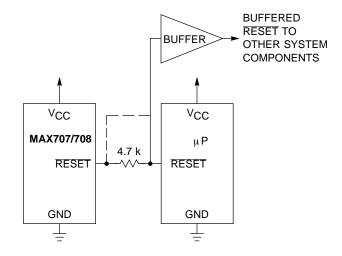


Figure 15. Interfacing to Bidirectional Reset I/O

Monitoring Additional Supply Levels

When connecting a voltage divider to PFI and adjusting it properly, you can monitor a voltage different than the unregulated DC one. As shown in Figure 16, to increase noise immunity, hysteresis may be added to the power–fail comparator just by a resistor between \overline{PFO} and \overline{PFI} . Not to unbalance the potential divider network, R3 should be 10 times the sum of the two resistors R1 and R2. If required, a capacitor between PFI and GND will reduce the sensitivity of the circuit to high–frequency noise on the line being monitored. The \overline{PFO} output may be connected to \overline{MR} input to generate a low level on the \overline{RESET} when V_{CC_1} drops out of tolerance. Thus a \overline{RESET} is generated when one of the two voltages is below its threshold level.

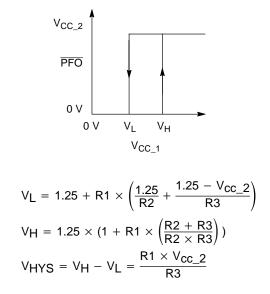


Figure 16. Monitoring Additional Supply Levels

ORDERING INFORMATION

Device	Marking	Reset V _{CC} Threshold (V)	Package	Shipping [†]
MAX707ESA-T	S707	4.63	SOIC-8	2500 Tape & Reel
MAX707ESA-TG	S707	4.63	SOIC-8 (Pb-Free)	2500 Tape & Reel
MAX708ESA-T	S708	4.38	SOIC-8	2500 Tape & Reel
MAX708ESA-TG	S708	4.38	SOIC-8 (Pb-Free)	2500 Tape & Reel
MAX708RESA-T	S708R	2.63	SOIC-8	2500 Tape & Reel
MAX708RESA-TG	\$708R	2.63	SOIC-8 (Pb-Free)	2500 Tape & Reel
MAX708SESA-T	S708S	2.93	SOIC-8	2500 Tape & Reel
MAX708SESA-TG	S708S	2.93	SOIC-8 (Pb-Free)	2500 Tape & Reel
MAX708TESA-T	S708T	3.08	SOIC-8	2500 Tape & Reel
MAX708TESA-TG	S708T	3.08	SOIC-8 (Pb-Free)	2500 Tape & Reel
MAX707CUA-T	SAC	4.63	Micro8	4000 Tape & Reel
MAX707CUA-TG	SAC	4.63	Micro8 (Pb-Free)	4000 Tape & Reel
MAX708CUA-T	SAD	4.38	Micro8	4000 Tape & Reel
MAX708CUA-TG	SAD	4.38	Micro8 (Pb-Free)	4000 Tape & Reel
MAX708RCUA-T	SAG	2.63	Micro8	4000 Tape & Reel
MAX708RCUA-TG	SAG	2.63	Micro8 (Pb-Free)	4000 Tape & Reel
MAX708SCUA-T	SAF	2.93	Micro8	4000 Tape & Reel
MAX708SCUA-TG	SAF	2.93	Micro8 (Pb-Free)	4000 Tape & Reel
MAX708TCUA-T	SAE	3.08	Micro8	4000 Tape & Reel
MAX708TCUA-TG	SAE	3.08	Micro8 (Pb-Free)	4000 Tape & Reel

[†]For information on tape and reel specifications,including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



SOIC-8 NB CASE 751-07 **ISSUE AK**

DATE 16 FEB 2011



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
- MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE
- DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
- 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

	MILLIMETERS		INC	INCHES	
DIM	MIN	MAX	MIN	MAX	
Α	4.80	5.00	0.189	0.197	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.053	0.069	
D	0.33	0.51	0.013	0.020	
G	1.27	7 BSC	0.05	0 BSC	
Н	0.10	0.25	0.004	0.010	
J	0.19	0.25	0.007	0.010	
K	0.40	1.27	0.016	0.050	
М	0 °	8 °	0 °	8 °	
N	0.25	0.50	0.010	0.020	
S	5.80	6.20	0.228	0.244	

SOLDERING FOOTPRINT*



^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code = Assembly Location

= Wafer Lot = Year = Work Week

= Pb-Free Package



XXXXXX = Specific Device Code = Assembly Location Α

= Year ww = Work Week

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

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SOIC-8 NB CASE 751-07 ISSUE AK

DATE 16 FEB 2011

STYLE 3: PIN 1. DRAIN, PIE #1 CTOR, #1 CTOR, #2 CTOR, #1 CTOR, #2 CTOR, #2 CTOR, #2 CTOR, #2 CTOR, #1	2. ANODE 3. ANODE 4. ANODE 5. ANODE 6. ANODE 7. ANODE 8. COMMON CATHODE STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 3. BASE, #2 4. COLLECTOR, #2 5. COLLECTOR, #2 6. EMITTER, #1 Vd STYLE 12: PIN 1. SOURCE 2. SOURCE 3. SOURCE 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN 8. TYLE 16: PIN 1. EMITTER, DIE #1 2. BASE, DIE #1 3. EMITTER, DIE #1 4. ANODE 5. ANODE 6. ANODE 7. ANODE 7. ANODE 7. ANODE 7. ANODE 8. COMMON CATHODE 8. COMMON CATHODE 9. ANODE 7. ANODE 8. COMMON CATHODE 9. ANODE 9. ANO
E PIN 1. INPUT 2. EXTERNAL BY 3. THIRD STAGE 4. GROUND E 5. DRAIN 6. GATE 3 7. SECOND STAGE 8. FIRST STAGE STYLE 11: ID PIN 1. SOURCE 1 2. GATE 1 T 3. SOURCE 2 ID 4. GATE 2 ID 5. DRAIN 2 6. DRAIN 2 7. DRAIN 1 ID 8. DRAIN 1 ID	PIN 1. COLLECTOR, DIE #1 2. BASE, #1 3. BASE, #2 4. COLLECTOR, #2 5. COLLECTOR, #2 6. EMITTER, #2 7. EMITTER, #1 Vd 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE 2. SOURCE 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN 8. TYLE 16: PIN 1. EMITTER, DIE #1 2. BASE, DIE #1 3. EMITTER, DIE #2
ID PIN 1. SOURCE 1 2. GATE 1 T 3. SOURCE 2 ID 4. GATE 2 ID 5. DRAIN 2 6. DRAIN 2 7. DRAIN 1 ID 8. DRAIN 1 STYLE 15: RCE PIN 1. ANODE 1 E 2. ANODE 1 RCE 3. ANODE 1	PIN 1. SOURCE 2. SOURCE 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN STYLE 16: PIN 1. EMITTER, DIE #1 2. BASE, DIE #1 3. EMITTER, DIE #2
STYLE 15: RCE PIN 1. ANODE 1 E 2. ANODE 1 RCE 3. ANODE 1	PIN 1. EMITTER, DIE #1 2. BASE, DIE #1 3. EMITTER, DIE #2
N 7. CATHODE, CON N 8. CATHODE, CON	MMON 5. COLLECTOR, DIE #2 MMON 6. COLLECTOR, DIE #2 MMON 7. COLLECTOR, DIE #1 MMON 8. COLLECTOR, DIE #1
STYLE 19: PIN 1. SOURCE 1 E 2. GATE 1 E 3. SOURCE 2 4. GATE 2 5. DRAIN 2 6. MIRROR 2 DE 7. DRAIN 1 DE 8. MIRROR 1	STYLE 20: PIN 1. SOURCE (N) 2. GATE (N) 3. SOURCE (P) 4. GATE (P) 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN
STYLE 23: E1 PIN 1. LINE 1 IN DN CATHODE/VCC 2. COMMON ANC DN CATHODE/VCC 3. COMMON ANC E3 4. LINE 2 IN DN ANODE/GND 5. LINE 2 OUT E4 6. COMMON ANC E5 7. COMMON ANC DN ANODE/GND 8. LINE 1 OUT	ODE/GND 2. EMITTER ODE/GND 3. COLLECTOR/ANODE
STYLE 27: PIN 1. ILIMIT 2. OVLO 3. UVLO 4. INPUT+ 5. SOURCE 6. SOURCE 6. SOURCE 7. SOURCE 8. DRAIN	STYLE 28: PIN 1. SW_TO_GND 2. DASIC_OFF 3. DASIC_SW_DET 4. GND 5. V MON 6. VBULK 7. VBULK 8. VIN
1 1	
;	STYLE 27: PIN 1. ILIMIT 2. OVLO 3. UVLO 4. INPUT+ E 5. SOURCE E 6. SOURCE E 7. SOURCE 8. DRAIN

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Micro8 CASE 846A-02 ISSUE K

DATE 16 JUL 2020









NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- CONTROLLING DIMENSION: MILLIMETERS
- DIMENSION 6 DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.10 mm IN EXCESS OF MAXIMUM MATERIAL CONDITION.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSION OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 mm PER SIDE. DIMENSION E DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 mm PER SIDE. DIMENSIONS D AND E ARE DETERMINED AT DATUM F.
- DATUMS A AND B ARE TO BE DETERMINED AT DATUM F.
- A1 IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.



MOUNTING FOOTPRINT

DIM	MI	LLIMETE	RS
ויונע	MIN.	N□M.	MAX.
Α	-	-	1.10
A1	0.05	0.08	0.15
b	0.25	0.33	0.40
c	0.13	0.18	0.23
D	2.90	3.00	3.10
E	2.90	3.00	3.10
е	0.65 BSC		
HE	4.75	5.05	
L	0.40	0.55	0.70

GENERIC MARKING DIAGRAM*



XXXX = Specific Device Code Α = Assembly Location

Υ = Year W = Work Week = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:	STYLE 2:	STYLE 3:
PIN 1. SOURCE	PIN 1. SOURCE 1	PIN 1. N-SOURCE
SOURCE	2. GATE 1	2. N-GATE
SOURCE	3. SOURCE 2	3. P-SOURCE
GATE	4. GATE 2	4. P-GATE
DRAIN	5. DRAIN 2	5. P-DRAIN
DRAIN	6. DRAIN 2	6. P-DRAIN
7. DRAIN	7. DRAIN 1	7. N-DRAIN
8. DRAIN	8. DRAIN 1	8. N-DRAIN

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